

# 65nm CMOS Process Data Sheet for the Analog IC Design Course

Note: The parameters in this sheet are representative for a 65nm CMOS process, and are intended for teaching purposes only.

| Transistor Parameters     |   |   |                          |
|---------------------------|---|---|--------------------------|
| Parameter                 | NMOS  | PMOS  | Unit                     |
| Gain factor               | $k_n = 440$                                     | $k_p = 140$                                     | $\mu\text{A}/\text{V}^2$ |
| Threshold voltage         | $V_{t0n} = 0.3$                                 | $V_{t0p} = -0.3$                                | V                        |
| Body effect factor        | $\gamma_n = 0.24$                               | $\gamma_p = -0.20$                              | $\sqrt{V}$               |
| Surface potential         | $2\phi_{fn} = 1.3$                              | $2\phi_{fp} = -1.0$                             | V                        |
| Channel length modulation | $\left  \frac{dX_{d,n}}{dV_{DS}} \right  = 0.2$ | $\left  \frac{dX_{d,p}}{dV_{DS}} \right  = 0.2$ | $\mu\text{m}/\text{V}$   |
| Subthreshold current      | $I_{tn} = 1.7$                                  | $I_{tp} = -0.45$                                | $\mu\text{A}$            |
| Subthreshold slope factor | $n_n = 1.7$                                     | $n_p = 1.5$                                     |                          |

| Capacitances (layer to substrate) |                                    |                                       |
|-----------------------------------|------------------------------------|---------------------------------------|
|                                   | Area ( $\text{fF}/\mu\text{m}^2$ ) | Perimeter ( $\text{fF}/\mu\text{m}$ ) |
| Gate oxide capacitance            | $C_{ox} = 12$                      |                                       |
| Gate-diffusion overlap            |                                    | $C_{ol}/W = 0.3$                      |
| N+ diffusion (0V)                 | $C_{j0n} = 1.4$                    | $C_{jswn} = 0.04$                     |
| P+ diffusion (0V)                 | $C_{j0p} = 1.8$                    | $C_{jswp} = 0.06$                     |
| Poly                              | $C_p = 0.11$                       | $C_{pp} = 0.018$                      |
| Metal 1                           | $C_{m1} = 0.098$                   | $C_{m1p} = 0.018$                     |
| Metal 2                           | $C_{m2} = 0.062$                   | $C_{m2p} = 0.018$                     |
| Metal 3                           | $C_{m3} = 0.033$                   | $C_{m3p} = 0.016$                     |
| Metal 4                           | $C_{m4} = 0.022$                   | $C_{m4p} = 0.015$                     |
| Metal 5                           | $C_{m5} = 0.017$                   | $C_{m5p} = 0.015$                     |
| Metal 6                           | $C_{m6} = 0.014$                   | $C_{m6p} = 0.015$                     |
| Metal 7                           | $C_{m7} = 0.009$                   | $C_{m7p} = 0.016$                     |
| Metal 8                           | $C_{m8} = 0.007$                   | $C_{m8p} = 0.018$                     |

| Resistances                            |                     |                                  |                     |
|--|---------------------|----------------------------------|---------------------|
| Sheet resistances ( $\Omega/\square$ ) |                     | Contact resistances ( $\Omega$ ) |                     |
| Poly                                   | $R_{sp} = 15$       | Contact Metal1 to below          | $R_{ct} = 38$       |
| Metal 1                                | $R_{sm1} = 0.13$    | Via MetalX to X+1, X=1..5        | $R_{via1-5} = 1.0$  |
| Metal2-5                               | $R_{sm2-5} = 0.11$  | Via MetalX to X+1, X=6..7        | $R_{via6-7} = 0.50$ |
| Metal6                                 | $R_{sm6} = 0.040$   |                                  |                     |
| Metal7-8                               | $R_{sm7-8} = 0.024$ |                                  |                     |

| Maximum currents                              |                  |                           |                     |
|---|------------------|---------------------------|---------------------|
| Current densities ( $\text{mA}/\mu\text{m}$ ) |                  | Contact currents (mA)     |                     |
| Poly  | $J_p = 1.5$      | Contact Metal 1 to below  | $I_{ct} = 0.14$     |
| Metal1  | $J_{m1} = 1.5$   | Via MetalX to X+1, X=1..4 | $I_{via1-4} = 0.16$ |
| Metal2-5                                      | $J_{m2-5} = 1.8$ | Via Metal5 to 6           | $I_{via5} = 0.80$   |
| Metal6  | $J_{m6} = 4.4$   | Via MetalX to X+1, X=6..7 | $I_{via6-7} = 3.0$  |
| Metal7-8                                      | $J_{m7-8} = 8.0$ |                           |                     |